



PJQ1905

60V P-Channel Enhancement Mode Mosfet

Voltage **-60 V** **Current** **-500mA**

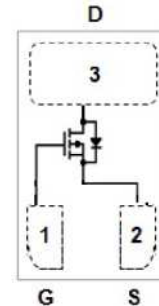
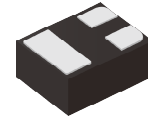
Features

- $R_{DS(ON)}$, $V_{GS}@-10V$, $I_D@-500mA < 4\Omega$
- $R_{DS(ON)}$, $V_{GS}@-4.5V$, $I_D@-200mA < 6\Omega$
- $R_{DS(ON)}$, $V_{GS}@-2.5V$, $I_D@-50mA < 13\Omega$
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case: DFN 3L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.00004 ounces, 0.0011 grams

DFN 3L



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	-60	V
Gate-Source Voltage		V _{GS}	±20	
Continuous Drain Current		I _D	-500	mA
Pulsed Drain Current, t _p ≤10us		I _{DM}	-1000	
Power Dissipation	T _a =25°C	P _D	500	mW
	Derate above 25°C		4	mW/°C
Operating Junction and Storage Temperature Range		T _J , T _{STG}	-55~150	°C
Typical Thermal Resistance		R _{θJA}	250	°C/W
- Junction to Ambient (Note 3)				



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Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-60	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250uA	-1	-1.5	-2.5	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-500mA	-	2.4	4	Ω
		V _{GS} =-4.5V, I _D =-200mA	-	2.65	6	
		V _{GS} =-2.5V, I _D =-50mA	-	4.5	13	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-48V, V _{GS} =0V	-	-	-1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	-	-	±100	nA
Dynamic (Note 5)						
Total Gate Charge	Q _g	V _{DS} =-25V, I _D =-100mA, V _{GS} =-4.5V (Note 2,3)	-	1.1	-	nC
Gate-Source Charge	Q _{gs}		-	0.3	-	
Gate-Drain Charge	Q _{gd}		-	0.2	-	
Input Capacitance	C _{iss}	V _{DS} =-25V, V _{GS} =0V, f=1MHZ	-	51	-	pF
Output Capacitance	C _{oss}		-	15	-	
Reverse Transfer Capacitance	C _{rss}		-	2.2	-	
Turn-On Delay Time	t _{d(on)}	V _{DD} =-25V, I _D =-100mA, V _{GS} =-10V, R _G =6Ω (Note 2,3)	-	4.8	-	ns
Turn-On Rise Time	t _r		-	19	-	
Turn-Off Delay Time	t _{d(off)}		-	52	-	
Turn-Off Fall Time	t _f		-	32	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I _S	---	-	-	-500	mA
Diode Forward Voltage	V _{SD}	I _S =-500mA, V _{GS} =0V	-	-0.95	-1.3	V

NOTES:

1. Pulse width ≤ 300us, Duty cycle ≤ 2%
2. Essentially independent of operating temperature typical characteristics.
3. R_{θJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 cm² FR-4 with 2oz. square pad of copper.
4. The maximum current rating is package limited.
5. Guaranteed by design, not subject to production testing.



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TYPICAL CHARACTERISTIC CURVES

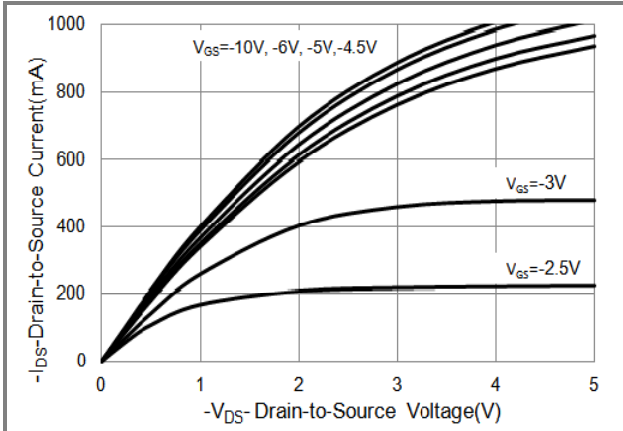


Fig.1 On-Region Characteristics

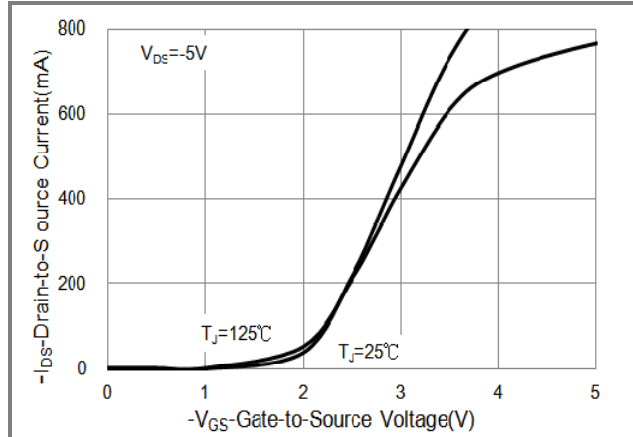


Fig.2 Transfer Characteristics

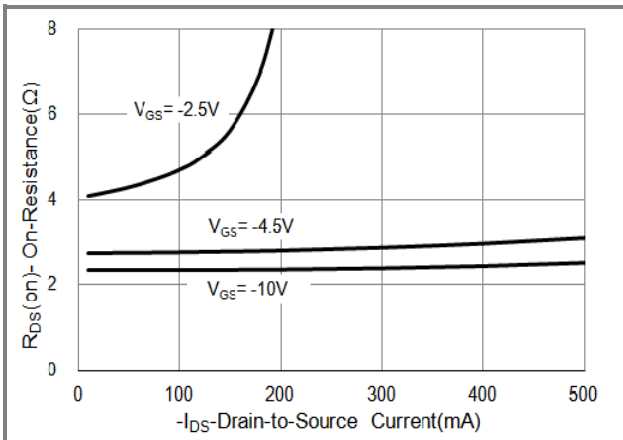


Fig.3 On-Resistance vs. Drain Current

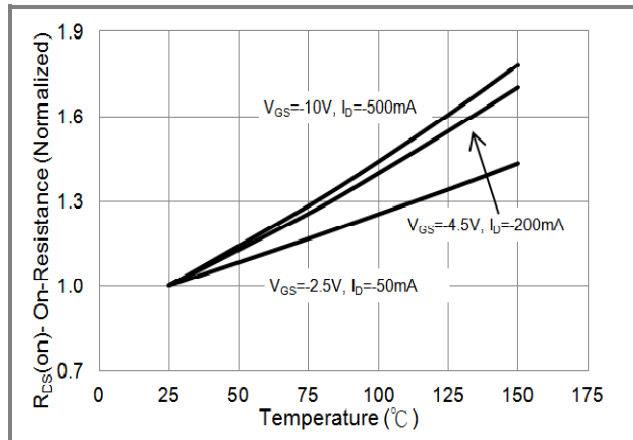


Fig.4 On-Resistance vs. Junction temperature

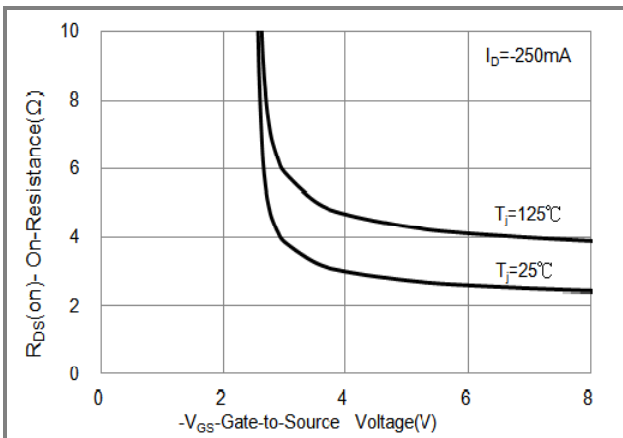


Fig.5 On-Resistance Variation with V_{GS}

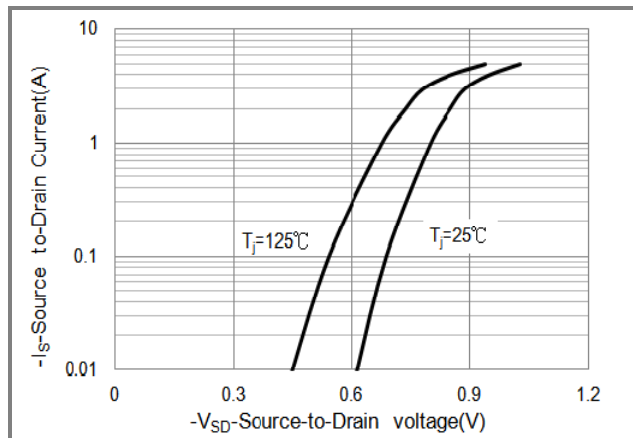


Fig.6 Body Diode Characteristics



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TYPICAL CHARACTERISTIC CURVES

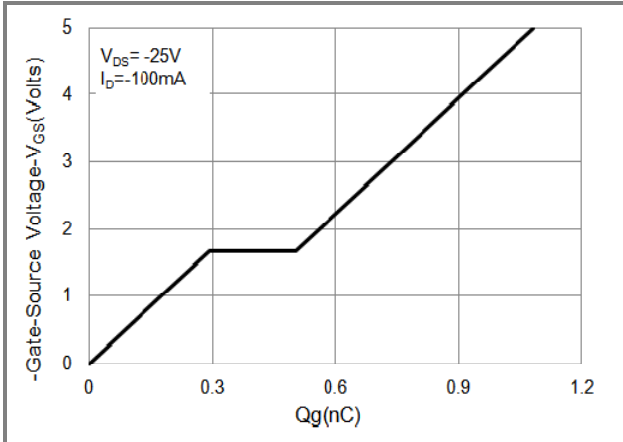


Fig.7 Gate-Charge Characteristics

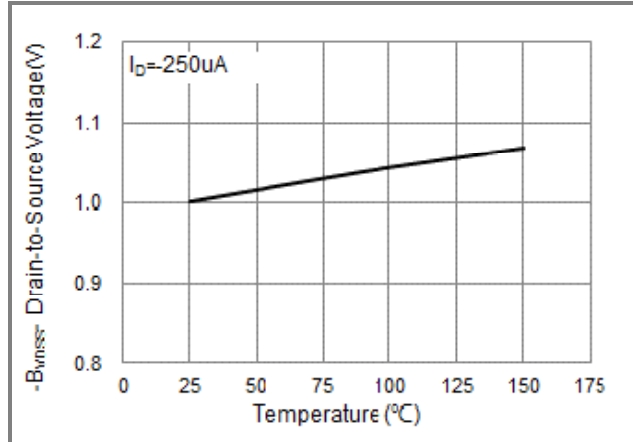


Fig.8 Breakdown Voltage Variation vs. Temperature

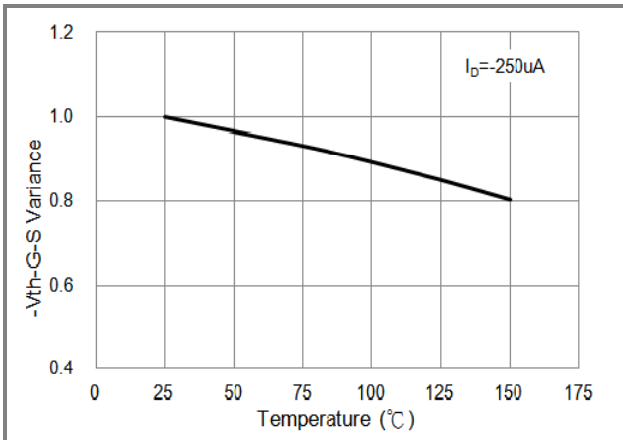


Fig.9 Threshold Voltage Variation with Temperature

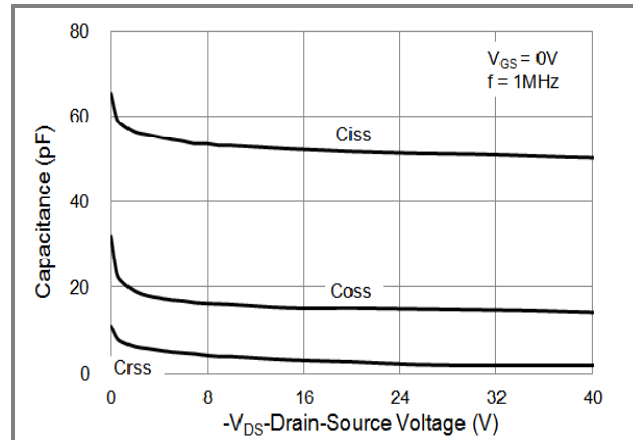


Fig.10 Capacitance vs. Drain-Source Voltage

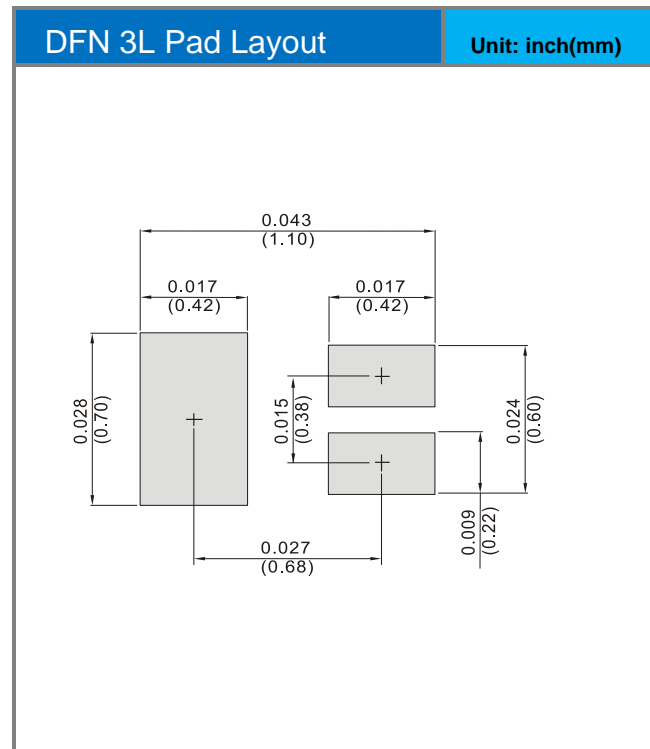
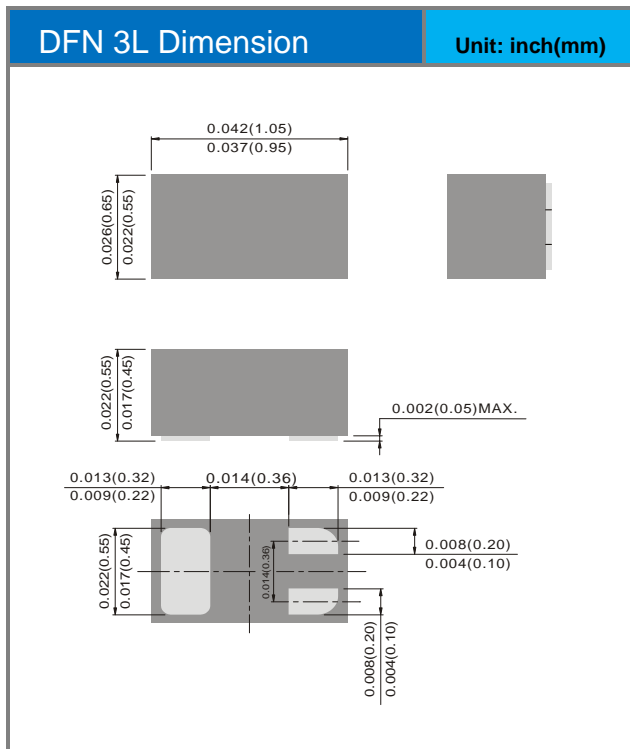


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Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJQ1905_R1_00001	DFN 3L	8K pcs / 7" reel	5	Halogen free

Packaging Information & Mounting Pad Layout





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